







Multilayer Optics for 1 nm to 13.5 nm: Can we reduce the litho wavelength further?

2018 International Workshop on EUV and soft X-Ray Sources

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- Multilayers for 1 nm ... 13.5 nm low reflectance, narrow bandwidth
- Narrow band sources meet narrow band multilayers
- Summary



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optiX fab.

History

- 1997: Start of EUV multilayer development @ Fraunhofer IOF
 2013: August 1st: Operations start @ optiX fab.
 TODAY: Delivery of 11,052 EUV and X-ray mirrors to customers
- Mission Fabrication of customized EUV optics and optical components for EUV lithography @ 13.5 nm, for EUV, soft and hard X-ray applications, synchrotron and FEL beamlines, metrology, R&D, HHG sources, etc.





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Multilayer mirror – principle of constructive interference



Mo/Si multilayer, TEM

50 nm

E. Spiller, *Low-loss reflection coatings using absorbing materials*, Appl. Phys. Lett. **20**, pp. 365-367, 1972.



Multilayers for 13.5 nm



Measured @PTB Berlin



ML coatings for short wavelengths

main issues for ML coatings at shorter wavelengths ($\lambda < 13.5$ nm):



1st: lower reflectance

typical experimental values for near normal incidence:

13.5 nm: $R \le 70 \%$

6.7 nm: $R \le 65 \%$

- 4.4 nm: $R \le 15 \%$
- 2.4 nm: $R \le 20 \%$



1st issue: lower reflectance at lower wavelengths

- real systems: reflection losses due to imperfect interfaces:
 - roughness
 - interdiffusion
 - formation of compounds



HR-TEM of a La/B-ML for 6.7 nm showing interdiffusion between La and B





1st issue: lower reflectance at lower wavelengths

- reflection losses due to imperfect interfaces
- higher losses for shorter wavelengths (stronger influence of interface regions)



high near normal incidence reflectivity (R > 60%) impossible at short wavelengths (λ < 6.6 nm)



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2nd: lower bandwidth





2nd issue: lower bandwidth at lower wavelengths

- strongly decreasing bandwidth (FWHM) of the ML coating for shorter wavelengths
- reason: higher number of required contributing interfaces



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2nd issue: lower bandwidth at lower wavelengths

- **strongly decreased bandwidth** (FWHM) of the ML coating for shorter wavelengths
- consequences:
 - wavelength matching between mirrors more complicated
 - Iower integrated reflection
 - lower photon throughput
 (assuming broad plasma sources)







Experimental results

| λ, nm | 1.4 | 2.4 | 2.7 | 4.4 | 6.7 | 9.0 | 12.0 | 13.5 |
|----------|-------|-------|-------|------|------|------|------|------|
| R, % | 0.02 | 18.1 | 26.2 | 16.8 | 61.0 | 36.0 | 49.2 | 70.1 |
| FWHM, nm | 0.002 | 0.005 | 0.008 | 0.02 | 0.05 | 0.11 | 0.32 | 0.52 |



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Multilayer development for water window collector





Collector mirror – today: Reflectance mapping at λ = 2.478 nm



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2018 multilayer collector mirror: Wavelength at different positions





2018 multilayer collector mirror: EUV reflectance at different radii



Measured @PTB Berlin



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- It's really hard to make high-reflective multilayers for wavelengths < 13.5 nm</p>
- Challenges: low reflectance, narrow bandwidth
- Please match source emission with multilayer absorption edges...



Still a very long and steep way to go ... but good to start now





KTH:

Hans Hertz and team

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Thomas Müller, Michael Scheler, Steffen Schulze











Thank you.

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